



Global Optoisolator™



6-Pin DIP Optoisolators Transistor Output

The CNY17-1, CNY17-2 and CNY17-3 devices consist of a gallium arsenide infrared emitting diode optically coupled to a monolithic silicon phototransistor detector.

- Closely Matched Current Transfer Ratio (CTR) to Minimize Unit-to-Unit Variation
- Guaranteed 70 Volt V(BR)CEO Minimum
- To order devices that are tested and marked per VDE 0884 requirements, the suffix "V" must be included at end of part number. VDE 0884 is a test option.

Applications

- Feedback Control Circuits, Open Loop Gain Control in Power Supplies
- Interfacing and coupling systems of different potentials and impedances
- General Purpose Switching Circuits
- Monitor and Detection Circuits

MAXIMUM RATINGS (TA = 25°C unless otherwise noted)

| Rating | Symbol | Value | Unit |
|--|------------------|-------------|-------------|
| INPUT LED | | | |
| Reverse Voltage | VR | 6 | Volts |
| Forward Current — Continuous | IF | 60 | mA |
| Forward Current — Pk (PW = 1 μ s, 330 pps) | IF(pk) | 1.5 | A |
| LED Power Dissipation @ TA = 25°C with Negligible Power In Output Detector Derate above 25°C | PD | 120 | mW |
| | | 1.41 | mW/°C |
| OUTPUT TRANSISTOR | | | |
| Collector-Emitter Voltage | VCEO | 70 | Volts |
| Emitter-Base Voltage | VEBO | 7 | Volts |
| Collector-Base Voltage | V _{CBO} | 70 | Volts |
| Collector Current — Continuous | IC | 100 | mA |
| Detector Power Dissipation @ TA = 25°C with Negligible Power In Input LED Derate above 25°C | PD | 150 | mW |
| | | 1.76 | mW/°C |
| TOTAL DEVICE | | | |
| Isolation Surge Voltage(1) (Peak ac Voltage, 60 Hz, 1 sec Duration) | VISO | 7500 | Vac(pk) |
| Total Device Power Dissipation @ TA = 25°C Derate above 25°C | PD | 250 2.94 | mW mW/°C |
| Ambient Operating Temperature Range(2) | TA | -55 to +100 | °C |
| Storage Temperature Range(2) | T _{stg} | -55 to +150 | °C |
| Soldering Temperature (10 sec, 1/16" from case) | T _L | 260 | °C |

1. Isolation surge voltage is an internal device dielectric breakdown rating.

For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.

2. Refer to Quality and Reliability Section In Opto Data Book for information on test conditions.

Preferred devices are Motorola recommended choices for future use and best overall value.

CNY17-1
[CTR = 40–80%]
CNY17-2*
[CTR = 63–125%]
CNY17-3*
[CTR = 100–200%]

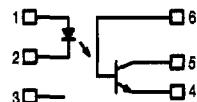
*Motorola Preferred Devices

STYLE 1 PLASTIC



STANDARD THRU HOLE
CASE 730A-04

SCHEMATIC



- PIN 1. LED ANODE
2. LED CATHODE
3. N.C.
4. Emitter
5. Collector
6. Base

CNY17-1 CNY17-2 CNY17-3
ELECTRICAL CHARACTERISTICS (TA = 25°C unless otherwise noted)⁽¹⁾

| Characteristic | Symbol | Min | Typ | Max | Unit |
|--|-------------------------|--------------------------------|--------------------------------|----------------------------------|---------|
| INPUT LED | | | | | |
| Forward Voltage (IF = 60 mA) | VF | — | 1.35 | 1.65 | Volts |
| TA = 25°C TA = -55°C TA = 100°C | | — — — | 1.5 1.25 | — | |
| Reverse Leakage Current (VR = 6 V) | IR | — | — | 10 | µA |
| Capacitance (V = 0, f = 1 MHz) | CJ | — | 18 | — | pF |
| OUTPUT TRANSISTOR | | | | | |
| Collector-Emitter Dark Current (VCE = 10 V, TA = 25°C) | ICEO | — | 5 | 50 | nA |
| (VCE = 10 V, TA = 100°C) | All devices | ICEO | — | 1.6 | — |
| Collector-Base Dark Current (VCB = 10 V) | ICBO | — | 0.5 | — | nA |
| Collector-Emitter Breakdown Voltage (IC = 1 mA) | V(BR)CEO | 70 | 120 | — | Volts |
| Collector-Base Breakdown Voltage (IC = 100 µA) | V(BR)CBO | 70 | 120 | — | Volts |
| Emitter-Base Breakdown Voltage (IE = 100 µA) | V(BR)EBO | 7 | 7.8 | — | Volts |
| DC Current Gain (IC = 2 mA, VCE = 5 V) (Typical Value) | hFE | — | 400 | — | — |
| Collector-Emitter Capacitance (f = 1 MHz, VCE = 0) | CCE | — | 8 | — | pF |
| Collector-Base Capacitance (f = 1 MHz, VCB = 0) | CCB | — | 21 | — | pF |
| Emitter-Base Capacitance (f = 1 MHz, VEB = 0) | CEB | — | 8 | — | pF |
| COUPLED | | | | | |
| Output Collector Current (IF = 10 mA, VCE = 5 V) | IC (CTR) ⁽²⁾ | 4 (40) 6.3 (63) 10 (100) | 8 (60) 10 (100) 15 (150) | 8 (80) 12.5 (125) 20 (200) | mA (%) |
| Collector-Emitter Saturation Voltage (IC = 2.5 mA, IF = 10 mA) | VCE(sat) | — | 0.18 | 0.4 | Volts |
| Delay Time (IF = 10 mA, VCC = 5 V, RL = 75 Ω, Figure 11) | td | — | 1.6 | 5.6 | µs |
| Rise Time (IF = 10 mA, VCC = 5 V, RL = 75 Ω, Figure 11) | tr | — | 1.6 | 4 | µs |
| Storage Time (IF = 10 mA, VCC = 5 V, RL = 75 Ω, Figure 11) | ts | — | 0.7 | 4.1 | µs |
| Fall Time (IF = 10 mA, VCC = 5 V, RL = 75 Ω, Figure 11) | tf | — | 2.3 | 3.5 | µs |
| Delay Time (IF = 20 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ (IF = 10 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ | td | — | 1.2 | 5.5 | µs |
| (IF = 20 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ (IF = 10 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ | CNY17-1 CNY17-2,3 | — — | 1.8 | 8 | |
| Rise Time (IF = 20 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ (IF = 10 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ | tr | — | 3.3 | 4 | µs |
| (IF = 20 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ (IF = 10 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ | CNY17-1 CNY17-2,3 | — — | 5 | 6 | |
| Storage Time (IF = 20 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ (IF = 10 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ | ts | — | 4.4 | 34 | µs |
| (IF = 20 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ (IF = 10 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ | CNY17-1 CNY17-2,3 | — — | 2,7 | 39 | |
| Fall Time (IF = 20 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ (IF = 10 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ | tf | — | 9.7 | 20 | µs |
| (IF = 20 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ (IF = 10 mA, VCC = 5 V, RL = 1 kΩ) ⁽³⁾ | CNY17-1 CNY17-2,3 | — — | 9.4, 20 | 24 | |
| Isolation Voltage (f = 60 Hz, t = 1 sec) ⁽⁴⁾ | VISO | 7500 | — | — | Vac(pk) |
| Isolation Resistance (V = 500 V) ⁽⁴⁾ | RISO | 10 ¹¹ | — | — | Ω |
| Isolation Capacitance (V = 0, f = 1 MHz) ⁽⁴⁾ | CISO | — | 0.2 | 0.5 | pF |

1. Always design to the specified minimum/maximum electrical limits (where applicable).

2. Current Transfer Ratio (CTR) = IC/IF × 100%.

3. For test circuit setup and waveforms, refer to Figure 11.

4. For this test, Pins 1 and 2 are common, and Pins 4, 5 and 6 are common.

CNY17-1 CNY17-2 CNY17-3

TYPICAL CHARACTERISTICS

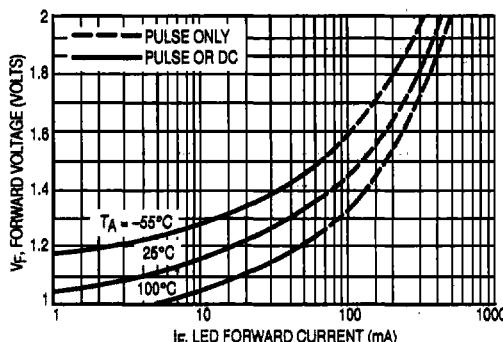


Figure 1. LED Forward Voltage versus Forward Current

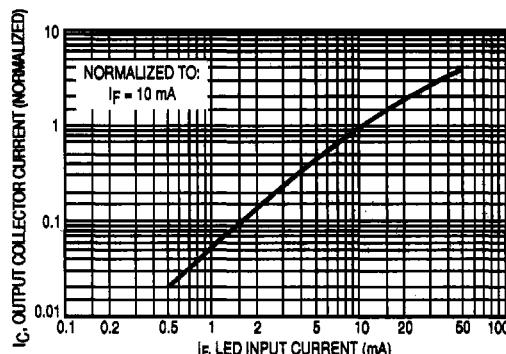


Figure 2. Output Current versus Input Current

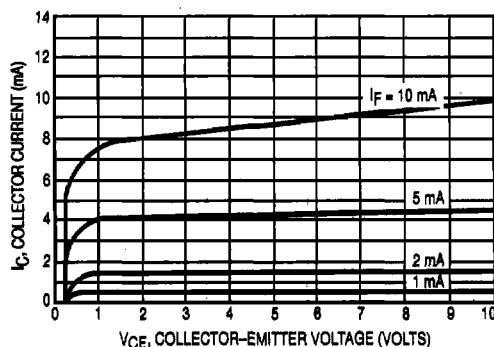


Figure 3. Collector Current versus Collector-Emitter Voltage

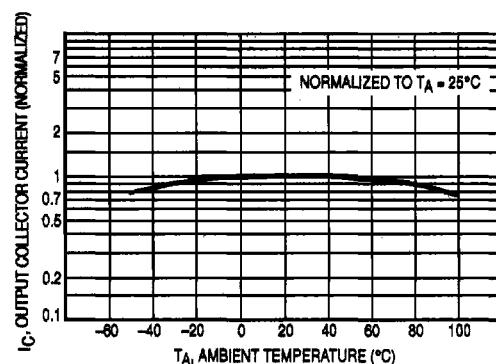


Figure 4. Output Current versus Ambient Temperature

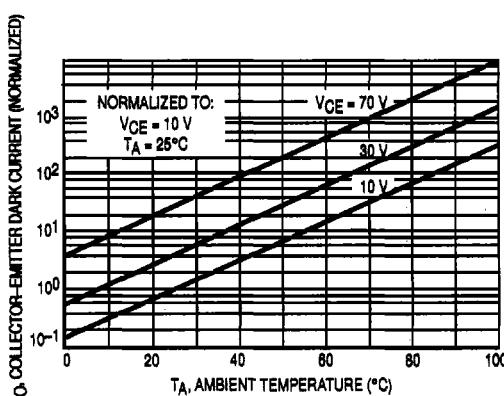


Figure 5. Dark Current versus Ambient Temperature

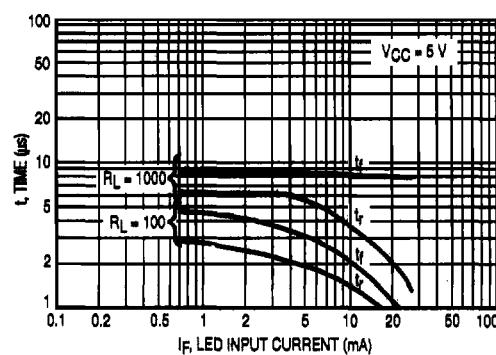


Figure 6. Rise and Fall Times
CNY17-1 and CNY17-2

CNY17-1 CNY17-2 CNY17-3

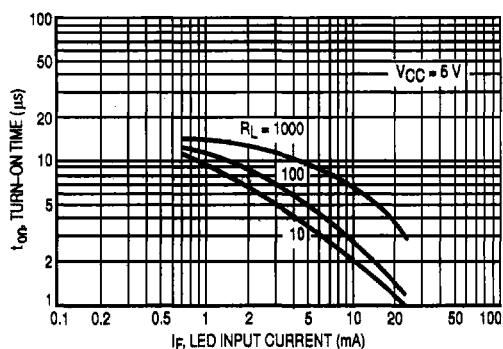


Figure 7. Turn-On Switching Times

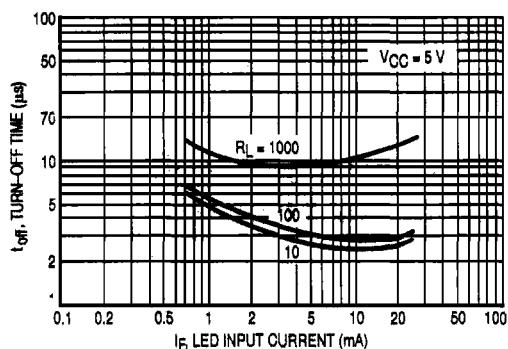


Figure 8. Turn-Off Switching Times
CNY17-1 and CNY17-2

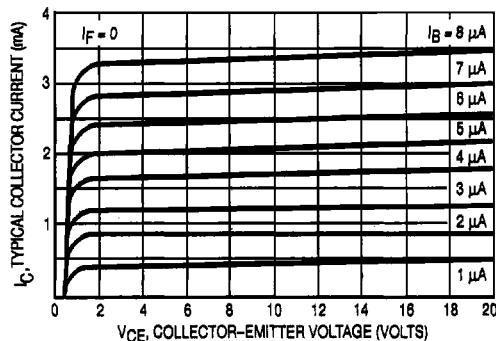


Figure 9. DC Current Gain (Detector Only)

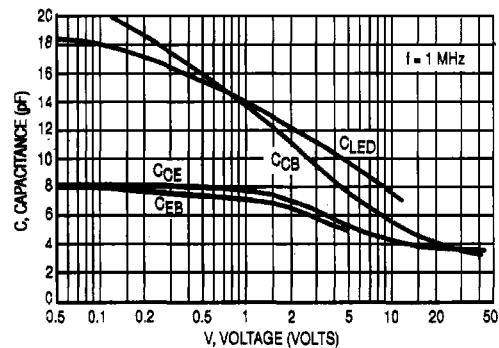


Figure 10. Capacitances versus Voltage

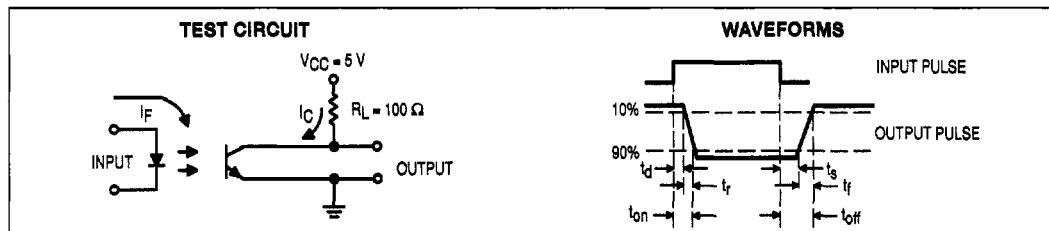


Figure 11. Switching Time Test Circuit and Waveforms